NSN 5961-00-173-1129

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.340 inches

Overall Diameter:

0.620 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

2.00 amperes source cutoff current

Power Rating Per Characteristic:

28.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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